









	<h2 style="color: red;">JAN1N5416US</h2>	
	Manufacturer Part Number:	JAN1N5416US
	Manufacturer/Brand:	Microsemi
	Part of Description:	DIODE GEN PURP 100V 3A AXIAL
Datasheets:	 JAN1N5416US.pdf	
RoHs Status:	Contains lead / RoHS non-compliant	
Stock Condition:	New original, Stock Available.	
Ship From:	Hong Kong	
Shipment Way:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Specifications

Part Number	JAN1N5416US
Manufacturer	Microsemi
Description	DIODE GEN PURP 100V 3A AXIAL
Category	Discrete Semiconductor Products > Diodes - Rectifiers -
Part Status	Require For Quote & Check Stock
Voltage - Forward (Vf) (Max) @ If	1.5V @ 9A
Voltage - DC Reverse (Vr) (Max)	100V
Speed	Fast Recovery = 200mA (Io)
Series	Military, MIL-PRF-19500/411
Reverse Recovery Time (trr)	150ns
Packaging	Bulk
Package / Case	B, Axial
Operating Temperature - Junction	-65°C ~ 175°C
Mounting Type	Through Hole
Diode Type	Standard
Current - Reverse Leakage @ Vr	1µA @ 100V
Current - Average Rectified (Io)	3A
Capacitance @ Vr, F	-

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RFQ JAN1N5416US Email: Info@Y-IC.com

You May Be Also Be interested

<p>In:</p>  <p>JAN1N5415 Microsemi Corporation DIODE GEN PURP 50V 3A AXIAL</p>	 <p>JAN1N5314UR-1 Microsemi Corporation DIODE CURRENT REG 100V</p>	 <p>JAN1N5314-1 Microsemi Corporation DIODE CURRENT REG 100V</p>	 <p>JAN1N5417US Microsemi Corporation DIODE GEN PURP 200V 3A B-MELF</p>
 <p>JAN1N5419 Microsemi Corporation DIODE GEN PURP 500V 3A AXIAL</p>	 <p>JAN1N5418US Microsemi Corporation DIODE GEN PURP 400V 3A D5B</p>	 <p>JAN1N5416 Microsemi Corporation DIODE GEN PURP 100V 3A AXIAL</p>	 <p>JAN1N5417 Microsemi Corporation DIODE GEN PURP 200V 3A AXIAL</p>

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JAN1N5416US Price	JAN1N5416US Manufacturer	JAN1N5416US Picture	JAN1N5416US Stock	JAN1N5416US Inventory
JAN1N5416US New	JAN1N5416US Original	JAN1N5416US Warranted	JAN1N5416US RFQ	JAN1N5416US Order Online

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